



PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

the Application of

Satoshi INOUE

Group Art Unit: 2811

Application No.: 10/814,169

Filed: April 1, 2004

Docket No.: 119330

For: METHOD OF MANUFACTURING SEMICONDUCTOR DEVICE, INTEGRATED CIRCUIT, ELECTRO-OPTICAL DEVICE, AND ELECTRONIC APPARATUS

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

Pursuant to 37 CFR §1.56, the attention of the Patent and Trademark Office is hereby directed to the references listed on the attached PTO-1449. Unless otherwise indicated herein, one copy of each reference is attached. It is respectfully requested that the information be expressly considered during the prosecution of this application, and that the references be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

- 1. This Information Disclosure Statement is being filed (a) within three months of the U.S. filing date of this non-CPA application, OR (b) before the mailing date of a first Office Action on the merits in the present application. No certification or fee is required.
- 2. Relevance of the non-English language references 1 and 2 are discussed in the present specification.

Respectfully submitted,

James A. Oliff  
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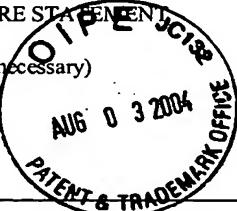
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Date: August 3, 2004

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Form PTO-1449 (REV. 8-83)		US Dept. of Commerce PATENT & TRADEMARK OFFICE	ATTY DOCKET NO. 119330	APPLICATION NO. 10/814,169		
INFORMATION DISCLOSURE STATEMENT  (Use several sheets if necessary)						
		APPLICANT Satoshi INOUE				
		FILING DATE April 1, 2004	GROUP 2811			
U.S. PATENT DOCUMENTS						
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS
FOREIGN PATENT DOCUMENTS						
		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB CLASS
OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)						
	1	"Single Crystal Thin Film Transistors", IBM Technical Disclosure Bulletin, Aug. 1993, p. 257.				
	2	R. Ishihara et al., "Advanced Excimer-Laser Crystallization Techniques of Si Thin-Film For Location Control of Large Grain on Glass", proc. SPIE 2001, Vol. 4295, pp. 14-23.				
EXAMINER					DATE CONSIDERED	
Examiner: Initial if citation considered, whether or not citation is in conformance with M.P.E.P. 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.						